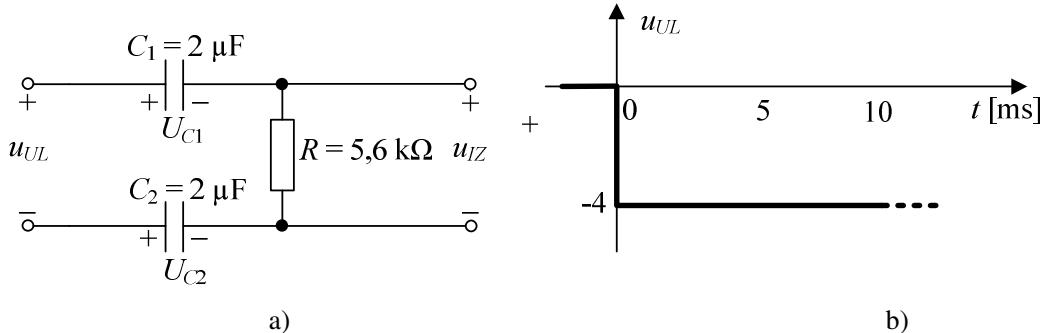


## MEĐUISPIT IZ ELEKTRONIKE 1

## ZADACI

**ZADATAK 1.** Za sklop na slici a) priključen je ulazni napon  $u_{UL}(t)$  prema slici b). U  $t = 0$  ms napon na kondenzatoru  $C_1$  iznosi  $U_{C1} = 1.5$  V dok na kondenzatoru  $C_2$  iznosi  $U_{C2} = 1.5$  V.

- Napisati izraz za izlazni napon u intervalu  $0 < t < \infty$  ms (**3 boda**).
- Izračunati vrijednosti izlaznog napona u  $t = 0$  ms i 5 ms (**2 boda**).
- Na istom grafu nacrtati ulazni i izlazni napon (**1 bod**).



**ZADATAK 2.** Silicij je dopiran donorima  $N_D = 2 \cdot 10^{16} \text{ cm}^{-3}$ . Odrediti:

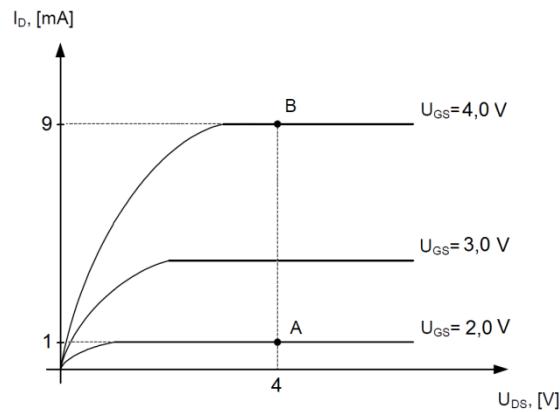
- položaj Fermijeve energije na temperaturi  $T = 300$  K (**2 boda**),
- tip i iznos koncentracije primjesa koju treba dodati da bi na  $T = 400$  K Fermijeva energija bila na istoj udaljenosti od vrha vodljivog pojasa kao pod a) (**4 boda**).

**ZADATAK 3.** Koncentracije primjesa na  $n$  i  $p$  strani silicijске diode iznose  $N_D = 4 \cdot 10^{15} \text{ cm}^{-3}$  i  $N_A = 2 \cdot 10^{17} \text{ cm}^{-3}$ . Parametri manjinskih nosilaca su  $\mu_n = 800 \text{ cm}^2/\text{Vs}$ ,  $\mu_p = 300 \text{ cm}^2/\text{Vs}$ ,  $\tau_n = 0,5 \mu\text{s}$  i  $\tau_p = 0,8 \mu\text{s}$ . Površina  $pn$  spoja iznosi  $S = 1 \text{ mm}^2$ . Širine  $n$  i  $p$  strane diode su  $W_n = 350 \mu\text{m}$  i  $W_p = 0,8 \mu\text{m}$ . Napon propusne polarizacije  $pn$ -spoja je  $U_D = 0,55$  V. Vrijedi  $T = 300$  K. Pretpostaviti  $m = 1$ .

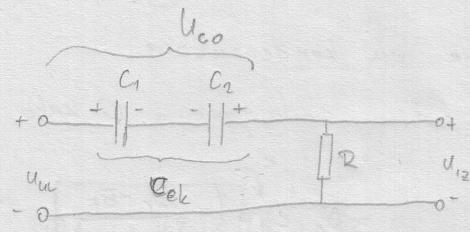
- Nacrtati raspodjele manjinskih nosilaca, izračunati i označiti rubne te ravnotežne koncentracije (**6 bodova**).
- Izračunati struju zasićenja  $I_S$  (**2 boda**).
- Izračunati iznos struje kroz diodu  $I_D$  (**1 bod**).
- Ako serijski otpor neutralnih p i n strana iznose redom  $5$  i  $7 \Omega$ , koliki je napon na stezaljakama diode  $U$  (**1 bod**)?

**ZADATAK 4.** Izlazna karakteristika nekog MOSFET-a prikazana je na slici. Faktor modulacije dužine kanala  $\lambda$  je približno jednak nuli.

- Uz obrazloženje, odrediti tip MOSFET-a ( $n$  ili  $p$  kanalni, obogaćeni ili osiromašeni) (**1 bod**).
- Izračunati napon praga  $U_{GS0}$  (**3 boda**).
- Izračunati debljinu oksida upravljačke elektrode  $t_{ox}$  ako je omjer širine i duljine kanala  $W/L = 20$ , te pokretljivost nosilaca  $\mu = 350 \text{ cm}^2/\text{Vs}$  (**2 boda**).
- Nacrtati prijenosnu karakteristiku i na njoj označiti položaj točaka A i B. (**2 bod**).



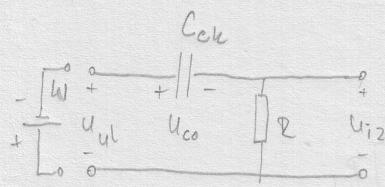
$$\textcircled{1} \quad U_{UL} = U_{C1} + U_{i_2} - U_{C2} = \\ = U_{C1} - U_{C2} + U_{i_2}$$



$$U_{c0} = U_{c10} - U_{c20}$$

$$C_{ek} = \left[ \frac{1}{C_1} + \frac{1}{C_2} \right]^{-1} = \left\{ C_1 = C_2 = C \right\} = \left[ \frac{1}{C} + \frac{1}{C} \right]^{-1} = \frac{C}{2} = \frac{2}{2} = 1 \mu F$$

$$\tau = C_{ek} \cdot R = 10^{-6} \cdot 5,6 \cdot 10^3 = 5,6 \cdot 10^{-3} s = 5,6 ms$$



$$U_{c0} = U_{c10} - U_{c20} = 1,5 - 1,5 = 0$$

$$t = 0^- \Rightarrow U_{i2}(0^-) = 0$$

$$t = 0^+ \Rightarrow U_{i2}(0^+) = -4V$$

$$U_{c0} = U_{c1} = 0$$

$$U_{ek} = -4V$$

$$U_{i2}(t) = U_R(t) = U_R(0^+) \exp \frac{-t}{\tau}$$

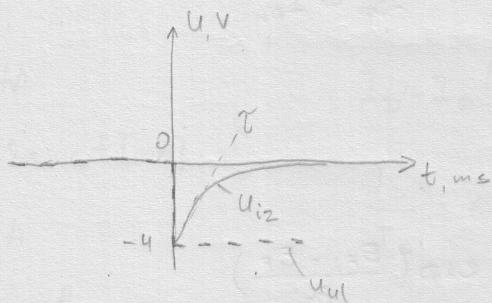
$$\text{b)} \quad U_{i2}(0^-) = 0$$

$$U_{i2}(0^+) = -4V$$

$$U_{i2}(t=5ms)$$

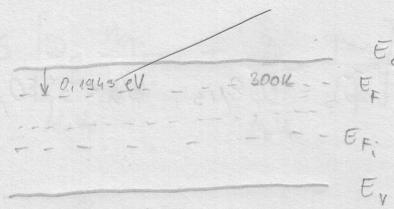
$$U_{i2} = -4 \exp \frac{-5 \cdot 10^{-3}}{5,6 \cdot 10^{-3}} = -1,64 V$$

c)



$$\textcircled{2} \quad N_D = 2 \cdot 10^{16} \text{ cm}^{-3}$$

a)  $T = 300K$   
 $E_F = ?$



b)  $T = 400K$

$$\text{a)} \quad n_{on} = N_c \cdot \exp \frac{E_F - E_C}{E_T} \Rightarrow E_F = E_C + E_T \ln \frac{n_{on}}{N_c}$$

$$N_D = 2 \cdot 10^{16} \text{ cm}^{-3} \quad n_i = 1,45 \cdot 10^{10} \text{ cm}^{-3} \Rightarrow N_D \gg n_i \Rightarrow \text{EKSTRINZIČAN}$$

$$n_{on} = N_D = 2 \cdot 10^{16} \text{ cm}^{-3}$$

$$N_c = C \cdot T^{\frac{3}{2}} = 7,07 \cdot 10^{15} \cdot (300)^{\frac{3}{2}} = 3,67 \cdot 10^{19} \text{ cm}^{-3}$$

$$E_F = E_C + E_T \ln \frac{n_{on}}{N_c} = E_C + \frac{300}{11600} \ln \frac{2 \cdot 10^{16}}{3,67 \cdot 10^{19}} = E_C - 0,1943 \text{ eV}$$

b)  $T \uparrow \Rightarrow E_F \Rightarrow E_{F_i}, \quad E_F \uparrow \Rightarrow N_D \uparrow$

$$N_{Duk} = N_{D1} + N_{D2}$$

$$T = 400K$$

$$N_c = C \cdot T^{\frac{3}{2}} = 7,07 \cdot 10^{15} \cdot 400^{\frac{3}{2}} = 5,66 \cdot 10^{19} \text{ cm}^{-3}$$

$$n_i(400K) = C \cdot T^{\frac{3}{2}} \exp \frac{-E_G}{2kT} = 7,22 \cdot 10^{12} \text{ cm}^{-3}$$

$$E_C - E_F = 0,1943 \text{ eV} \Rightarrow E_F - E_C = -0,1943 \text{ eV}$$

$$n_{on2} = N_c \exp \frac{E_F - E_C}{E_T} = 5,66 \cdot 10^{19} \exp \frac{-0,1943 \text{ eV}}{\frac{400}{11600}} = 1,02 \cdot 10^{17} \text{ cm}^{-3}$$

$$n_{on2} \gg n_i \Rightarrow \text{EKSTRINZIČAN}$$

$$n_{on2} \approx N_{Duk} = N_{D1} + N_{D2} \Rightarrow N_{D2} = n_{on2} - N_{D1}$$

$$N_{D2} = 1,82 \cdot 10^{17} \text{ cm}^{-3}$$

3) I<sub>S</sub>n-strana

$$N_D = 4 \cdot 10^{15} \text{ cm}^{-3}, \quad M_p = 300 \text{ cm}^2/\text{Vs}, \quad \tau_p = 0,8 \mu\text{s}, \quad W_n = 3,50 \mu\text{m} = 350 \cdot 10^{-4} \text{ cm}$$

p-strana

$$N_A = 2 \cdot 10^{17} \text{ cm}^{-3}, \quad M_n = 800 \text{ cm}^2/\text{Vs}, \quad \tau_n = 0,5 \mu\text{s}, \quad W_p = 0,8 \mu\text{m} = 0,8 \cdot 10^{-4} \text{ cm}$$

$$S = 1 \text{ mm}^2 = 10^{-2} \text{ cm}^2$$

a) RAVNOTEŽNE KONC.

$$p_{n0} = \frac{n_i^2}{N_{n0}} = \frac{n_i^2}{N_D} = \frac{(1,45 \cdot 10^{10})^2}{4 \cdot 10^{15}} = 5,26 \cdot 10^4 \text{ cm}^{-3}$$

$$n_{op} = \frac{n_i^2}{p_{n0}} = \frac{n_i^2}{N_A} = \dots = 1,05 \cdot 10^3 \text{ cm}^{-3}$$

RUBNE KONC.

$$p_{n0} = p_{n0} \exp \frac{U_0}{m U_T} = 5,26 \cdot 10^4 \exp \frac{0,55 \cdot 11600}{1 \cdot 300} = 9,06 \cdot 10^{13} \text{ cm}^{-3}$$

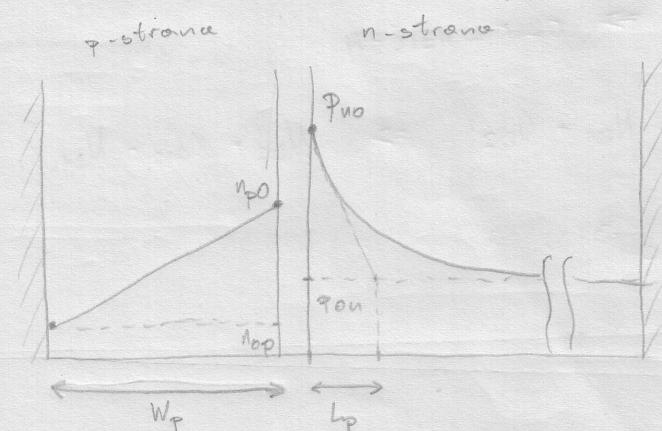
$$n_{p0} = n_{op} \exp \frac{U_0}{m U_T} = \dots = 1,81 \cdot 10^{12} \text{ cm}^{-3}$$

$$L_n = \sqrt{D_n \tau_n} = \sqrt{M_n U_T \tau_n} = \sqrt{800 \cdot \frac{300}{11600} \cdot 0,5 \cdot 10^{-6}} = 32,2 \mu\text{m} = 32,2 \cdot 10^{-4} \text{ cm}$$

$$L_p = \sqrt{D_p \tau_p} = \sqrt{M_p U_T \tau_p} = \dots = 24,9 \mu\text{m} = 24,9 \cdot 10^{-4} \text{ cm}$$

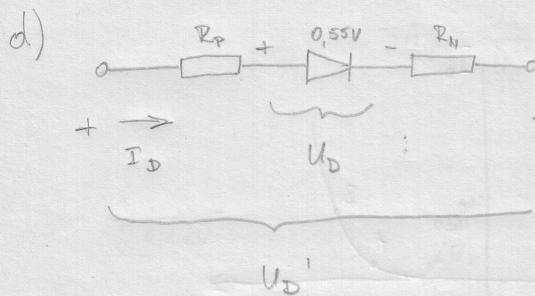
$W_p \ll L_n \Rightarrow$  USKA P-STRANA

$W_n \gg L_p \Rightarrow$  ŠIROKA N-STRANA



$$\begin{aligned}
 b) I_S &= I_{SN} + I_{SP} = qS \left[ \underbrace{D_n}_{M_n U_T} \frac{V_{OP}}{W_P} + \underbrace{D_P}_{M_P U_T} \frac{I_{on}}{L_P} \right] = qS U_T \left[ M_n \frac{V_{OP}}{W_P} + M_P \frac{I_{on}}{L_P} \right] = \\
 &= 1,6 \cdot 10^{-19} \cdot 10^{-2} \frac{300}{11600} \left[ 800 \frac{1,05 \cdot 10^3}{0,8 \cdot 10^{-4}} + 300 \frac{5,26 \cdot 10^4}{24,9 \cdot 10^{-4}} \right] = \\
 &= 0,7 \cdot 10^{-12} A = 0,7 \mu A
 \end{aligned}$$

$$c) I_D = I_S \left[ \exp\left(\frac{U_D}{mU_T}\right) - 1 \right] = 0,7 \cdot 10^{-12} \left[ \exp\left(\frac{0,55 \cdot 11600}{1 \cdot 300}\right) - 1 \right] = 1,2 \text{ mA}$$



$$U_D' = U_D + I_D (R_p + R_N) = 0,55 + 1,2 \cdot 10^{-3} (5 + 7)$$

$$U_D' = 0,564 \text{ V}$$

4. a)  $U_{GS}$  pozitivan  $\Rightarrow I_D \uparrow \Rightarrow NMOS$

- moramo znati  $U_{GSO}$

b) A:  $I_{DA} = 1mA$       B:  $I_{DB} = 9mA$

$$U_{GSA} = 2V$$

$$U_{GSB} = 4V$$

A i B u zasicanju

$$I_{DA} = \frac{k}{2} (U_{GSA} - U_{GSO})^2 \quad I_{DB} = \frac{k}{2} (U_{GSB} - U_{GSO})^2$$

$$\frac{I_{DB}}{I_{DA}} = \frac{(U_{GSB} - U_{GSO})^2}{(U_{GSA} - U_{GSO})^2}$$

$$\pm \sqrt{\frac{I_{DB}}{I_{DA}}} = \frac{U_{GSB} - U_{GSO}}{U_{GSA} - U_{GSO}}$$

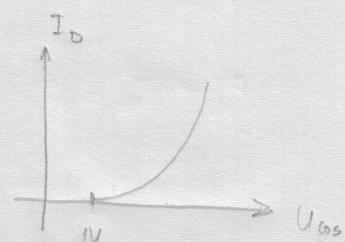
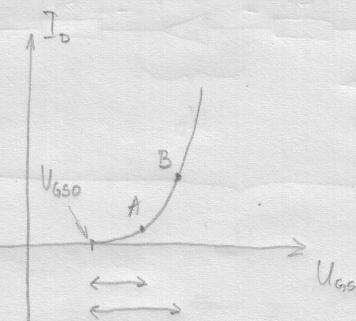
$$3 = \frac{U_{GSB} - U_{GSO}}{U_{GSA} - U_{GSO}}$$

$(U_{GSB} - U_{GSO})$  i  $(U_{GSA} - U_{GSO})$  imaju isti produkt.  
(i u A, i u B imamo kanal)

$$3(U_{GSA} - U_{GSO}) = U_{GSB} - U_{GSO} \Rightarrow U_{GSO} = \frac{3U_{GSA} - U_{GSB}}{2} = \frac{3 \cdot 2 - 4}{2} = 1V$$

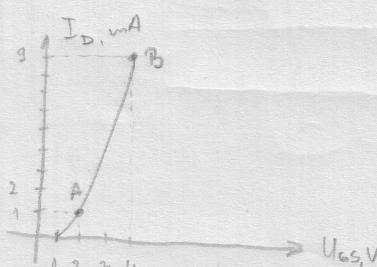
$$k = \frac{2 I_{D0}}{(U_{GSA} - U_{GSO})} = \dots = 2 \text{ mA V}^{-2}$$

u  $U_{GS} = 0V \Rightarrow I_D = 0 \Rightarrow$  OBODRACENI SLOJ



$$K = \mu_n C_{ox} \cdot \frac{W}{L} = \mu_n \frac{\epsilon_0 \epsilon_{r,ox}}{t_{ox}} \cdot \frac{W}{L} \Rightarrow t_{ox} = \frac{\mu_n \epsilon_0 \epsilon_{r,ox}}{K} \cdot \frac{W}{L}$$

$$t_{ox} = \frac{350 \cdot 8,854 \cdot 10^{-14} \cdot 3,9}{2 \cdot 10^{-3}} \cdot 20 = 1,21 \cdot 10^{-6} \text{ cm} = 12,1 \text{ nm}$$



## RJEŠENJA MEĐUISPITA IZ ELEKTRONIKE 1

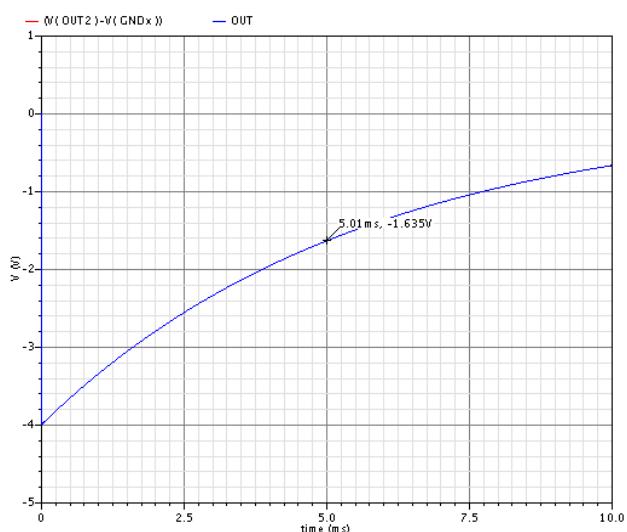
### ZADACI

#### ZADATAK 1.

$$u_{IZ}(0 \text{ ms} < t < \infty \text{ ms}) = u_{IZ}(0 \text{ ms})^+ \cdot e^{-\frac{t}{\tau}}$$

$$u_{IZ}(t = 3 \text{ ms}) = -1,96 \text{ V}$$

$$u_{IZ}(t = 5 \text{ ms}) = -1,64 \text{ V}$$



#### ZADATAK 2.

$$E_F = E_C - 0,1943 \text{ eV} \quad (2 \text{ boda})$$

$$E_F = E_{Fi} + 0,36 \text{ eV}$$

$$n_{02} = 2,02 \cdot 10^{17} \text{ cm}^{-3} \quad (2 \text{ boda})$$

$$N_{D2} = 1,82 \cdot 10^{17} \text{ cm}^{-3} \quad (2 \text{ boda})$$

#### ZADATAK 3.

$$n_{0p} = 1051,25 \text{ cm}^{-3}$$

$$D_n = 20,7 \text{ cm}^2/\text{s}$$

$$L_n = 3,22 \cdot 10^{-3} \text{ cm} = 32,2 \text{ um}$$

$$p_{0n} = 52\ 562,5 \text{ cm}^{-3}$$

$$D_p = 7,76 \text{ cm}^2/\text{s}$$

$$L_p = 2,49 \cdot 10^{-3} \text{ cm} = 24,9 \text{ um}$$

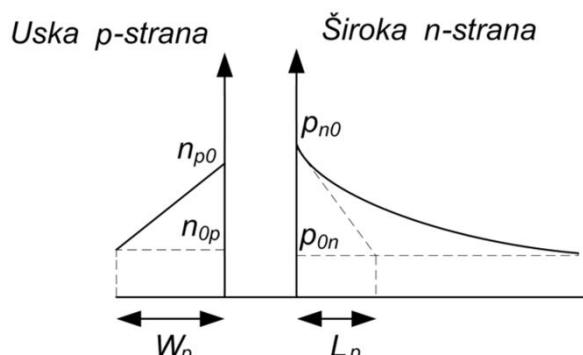
$$p_{n0} = 9,07 \cdot 10^{13} \text{ cm}^{-3}$$

$$n_{p0} = 1,81 \cdot 10^{12} \text{ cm}^{-3}$$

$$I_s = 0,7 \text{ pA}$$

$$I = 1,2 \text{ mA}$$

$$U = U_D + I * R_S = 0,56 \text{ V}$$

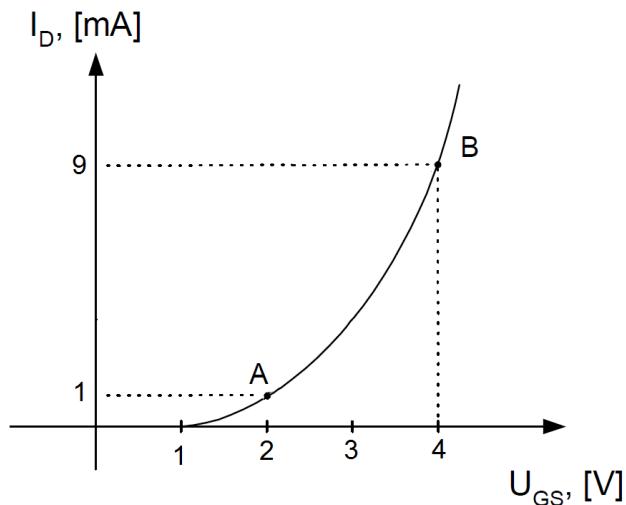


**ZADATAK 4.**

*n*-kanalni MOSFET obogaćenog tipa

$$U_{GS0} = 1 \text{ V}$$

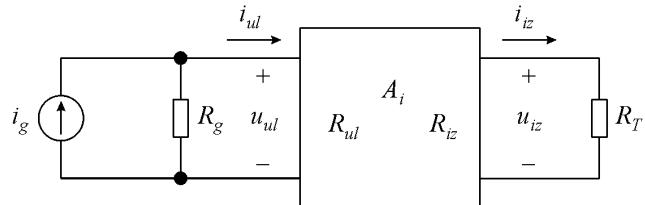
$$t_{ox} = 12,1 \text{ nm}$$



## PITANJA

**1.** Pojačalo na slici ima strujno pojačanje uz kratkospojen izlaz  $A_i = 150$ , ulazni otpor  $R_{ul} = 1 \text{ k}\Omega$  i izlazni otpor  $R_{iz} = 4 \text{ k}\Omega$ . Uz koji će otpor trošila  $R_T$  strujno pojačanje biti  $A_I = i_{iz}/i_{ul} = 100$ ? Koliko je pri tome naponsko pojačanje  $A_V = u_{iz}/u_{ul}$  (**2 boda**)?

- a)  $R_T = 8 \text{ k}\Omega, A_V = 200$
- b)  $R_T = 2 \text{ k}\Omega, A_V = 50$
- c)  $R_T = 8 \text{ k}\Omega, A_V = 100$
- d)  $R_T = 2 \text{ k}\Omega, A_V = 200$
- e)  $R_T = 8 \text{ k}\Omega, A_V = 50$



**2.** U siliciju dopiranom samo jednom primjesom koncentracije  $N$ , Fermijeva energija na  $T=300 \text{ K}$  nalazi se  $0,1 \text{ eV}$  od dna vodljivog pojasa. Na temperaturi  $T=400 \text{ K}$  vrijedi da je  $N \gg n_i$ . Za primjesu  $N$  te specifičnu vodljivost na  $T=400 \text{ K}$  u odnosu na  $T=300 \text{ K}$  vrijedi (**2 boda**):

- a)  $N$  su donori,  $\sigma$  pada
- b)  $N$  su akceptori,  $\sigma$  raste
- c)  $N$  su donori,  $\sigma$  raste
- d)  $N$  su akceptori,  $\sigma$  pada
- e)  $N$  su donori,  $\sigma$  se ne mijenja

**3.** *pn*-dioda sa širokim stranama ima *n*-stranu 1000 puta jače dopirano od *p*-strane i spojena je na napon  $U_D=0,6 \text{ V}$ . Da li je uz rub osiromašenog područja veća koncentracija manjinskih nosilaca na *p*-strani ili na *n*-strani? Ako se *p*-strana suzi na vrijednost  $W_p = L_n/10$ , što se dešava sa strujom diode (**2 boda**):

- a) Veća je koncentracija manjinskih nosilaca na *n*-strani; struja raste.
- b) Veća je koncentracija manjinskih nosilaca na *p*-strani; struja raste.
- c) Veća je koncentracija manjinskih nosilaca na *n*-strani; struja pada.
- d) Veća je koncentracija manjinskih nosilaca na *p*-strani; struja pada.
- e) Veća je koncentracija manjinskih nosilaca na *p*-strani; struja ostaje približno ista.

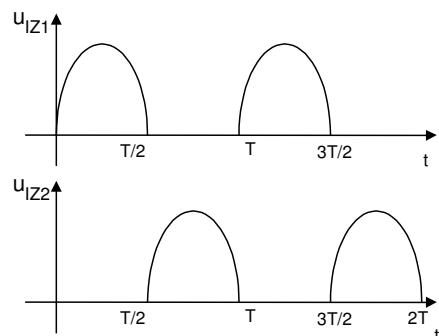
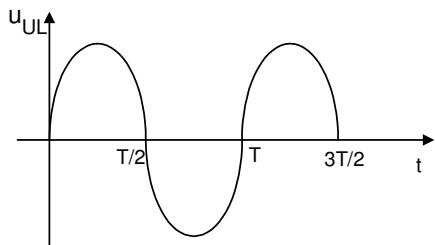
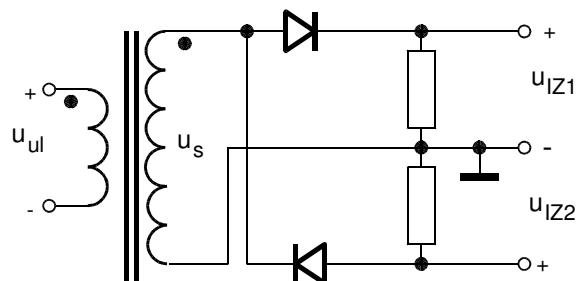
**4.** Kroz diodu koja ima struju zasićenja  $I_S=10 \text{ fA}$  teče struja  $i_D=1+0,2\sin\omega t \text{ [mA]}$ . Uz zanemarenje serijskog otpora neutralnih strana te pretpostavku  $U_T=25 \text{ mV}$ , napon na diodi ima sljedeći oblik (**2 boda**):

- a)  $u_D=630+5\cdot\sin\omega t, [\text{mV}]$
- b)  $u_D=700+25\cdot\sin\omega t, [\text{mV}]$
- c)  $u_D=700+5\cdot\sin\omega t, [\text{mV}]$
- d)  $u_D=550+5\cdot\sin\omega t, [\text{mV}]$
- e)  $u_D=630+25\cdot\sin\omega t, [\text{mV}]$

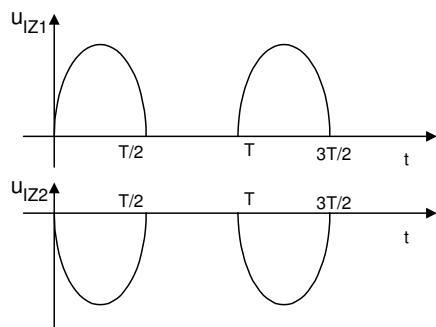
5. Koliku će valnu duljinu upadnog zračenja detektirati fotodioda sa širinom zabranjenog pojasa od 2,1 eV i kakva mora biti polarizacija fotodiode za tu detekciju (**2 boda**)?

- a)  $\lambda = 0,59 \mu\text{m}$ , zaporna polarizacija,
- b)  $\lambda = 1,7 \mu\text{m}$ , ne mora biti polarizirana
- c)  $\lambda = 1,7 \mu\text{m}$ , zaporna polarizacija
- d)  $\lambda = 1,7 \mu\text{m}$ , propusna polarizacija
- e)  $\lambda = 0,59 \mu\text{m}$ , propusna polarizacija

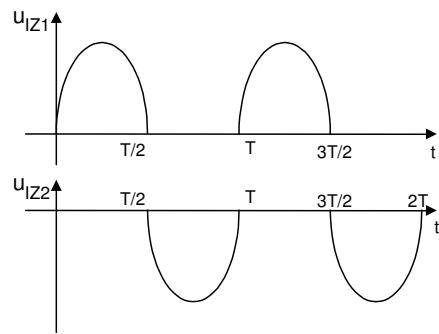
6. Na ulaz sklopa ispravljača priključen je sinusni ulazni napon. Kako izgledaju izlazni naponi (**2 boda**)?



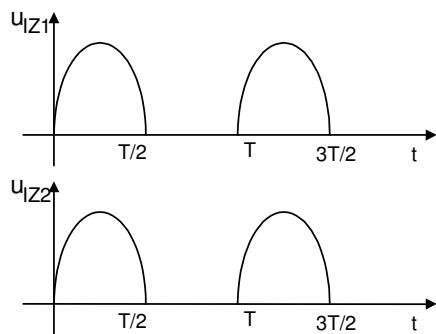
a)



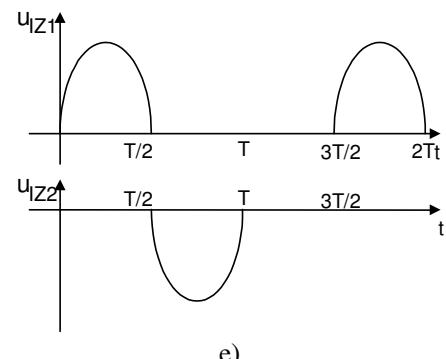
b)



c)

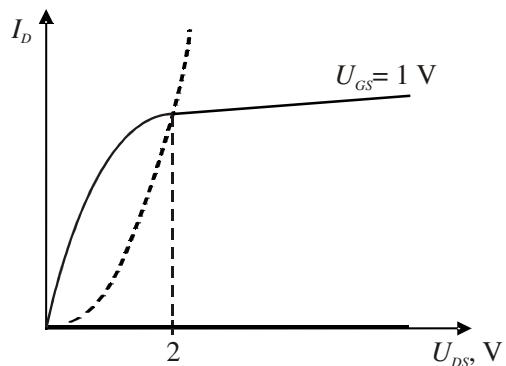


d)



e)

7. Na slici su prikazane izlazne karakteristike tranzistora. Za tip tranzistora vrijedi (**2 boda**):



- a.  $n$ -kanalni MOSFET obogaćenog tipa,
- b.  $p$ -kanalni MOSFET obogaćenog tipa,
- c.  $n$ -kanalni MOSFET osiromašenog tipa,
- d.  $p$ -kanalni MOSFET osiromašenog tipa,
- e.  $p$ -kanalni MOSFET u triodnom području.

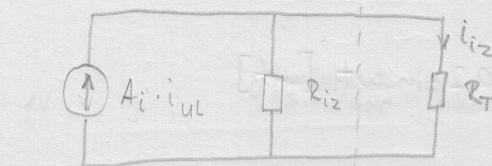
# PITANJA

$$\textcircled{1} \quad A_i = 150$$

$$R_{ul} = 1k\Omega$$

$$R_{iz} = 4k\Omega$$

$$A_I = \frac{i_{iz}}{i_{ul}} = 100$$

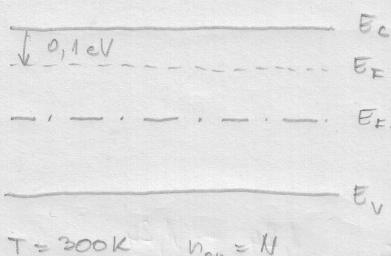


$$A_I = \frac{i_{iz}}{i_{ul}} = \frac{A_i \cdot i_{ul} \frac{R_{iz}}{R_{iz} + R_T}}{i_{ul}} \Rightarrow \frac{A_i}{A_I} = \frac{R_{iz} + R_T}{R_{iz}}$$

$$R_T = R_{iz} \left[ \frac{A_i}{A_I} - 1 \right] = 4 \left[ \frac{150}{100} - 1 \right] = 2k\Omega$$

$$A_v = \frac{U_{iz}}{U_{ul}} = \frac{i_{iz} R_T}{i_{ul} R_{ul}} = A_I \frac{R_T}{R_{ul}} = 100 \cdot \frac{2}{1} = 200$$

\textcircled{2}



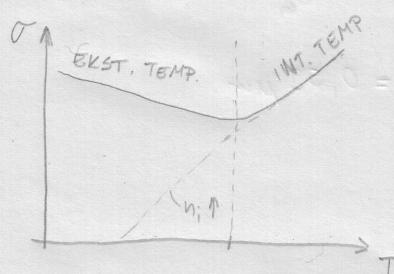
$$E_F > E_{F_i} \Rightarrow n\text{-tip} \quad N = N_D$$

$$T = 400K$$

$$N \gg n_i \Rightarrow n_{on} = N$$

$$T = T_N = q M_n \cdot n_{on} \xrightarrow{\text{KONST.}}$$

$$T \uparrow \Rightarrow M_n \downarrow \Rightarrow T \downarrow$$

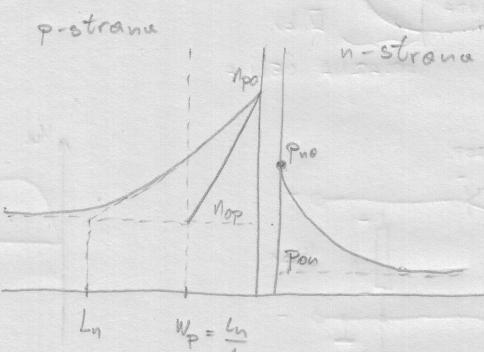


$$\textcircled{3} \quad N_D = 1000 N_A$$

$$p_{on} = \frac{n_i^2}{N_D} \ll n_{op} = \frac{n_i^2}{N_A}$$

n-strana

p-strana



1) ŠIROKA

$$I_{D1} = I_{DP} = q S D_n \frac{dn}{dx} = q S D_n \frac{n_{po}}{L_n}$$

$$2) \quad I_{D2} = I_{PP} = q S D_n \frac{n_{po}}{W_p}$$

$$\frac{I_{D2}}{I_{D1}} = \frac{L_n}{W_p} = \frac{L_n}{\frac{L_n}{10}} = 10$$

STRUJA RASTE

$$④ I_s = 10 \text{ fA} = 10 \cdot 10^{-15} \text{ A}$$

$$i_d = I_D + I_{dm} \cdot \sin \omega t = 1 + 0,2 \sin \omega t [\text{mA}]$$

$$I_D = 1 \text{ mA}$$

$$I_{dm} = 0,2 \text{ mA}$$

$$I_D = I_s \exp \frac{U_D}{U_T} \Rightarrow U_D = U_T \ln \frac{I_D}{I_s} = 25 \cdot \ln \frac{10^3}{10 \cdot 10^{-15}} = 633 \text{ mV} \approx 630 \text{ mV}$$

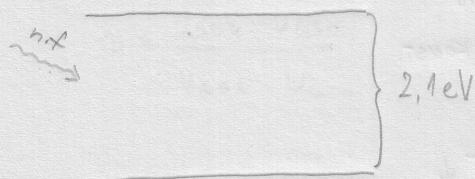
- Mali signal vidi dinamički otpor

$$r_d = \frac{U_T}{I_D} = \frac{25}{1} = 25 \Omega$$

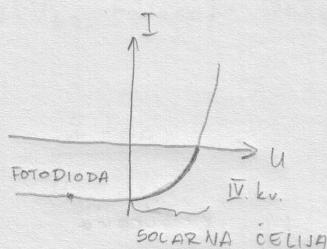
$$U_{dm} = r_d I_{dm} = 25 \cdot 0,2 \cdot 10^{-3} = 5 \cdot 10^{-3} \text{ V} = 5 \text{ mV}$$

$$U_D = U_D = U_D + U_{dm} \sin \omega t = 630 + 5 \sin \omega t [\text{mV}]$$

⑤

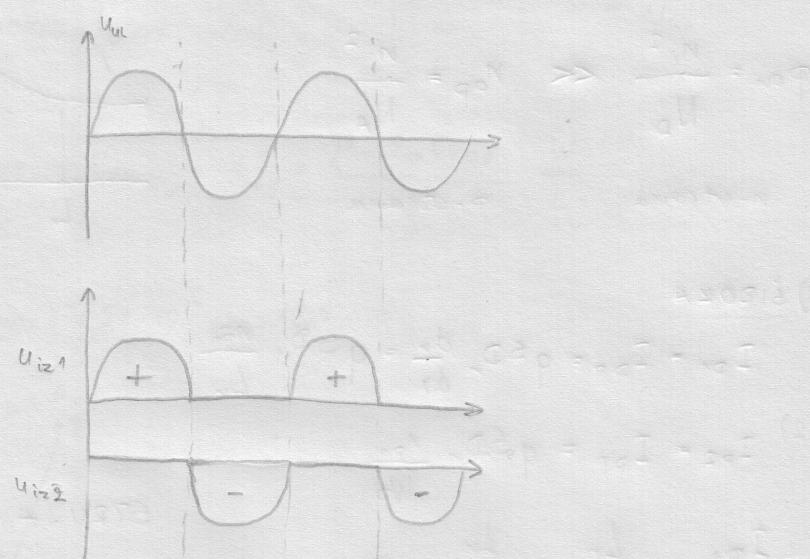
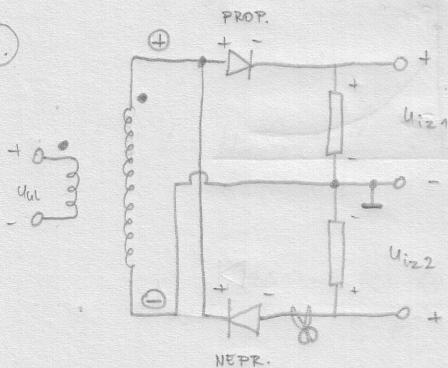


$$\left. \begin{aligned} h \cdot f &> E_g \\ h \cdot \frac{c}{\lambda} & \end{aligned} \right\} \lambda = \frac{hc}{E_g} = \frac{1,24}{E_g} = \frac{1,24}{2,1} \quad \lambda = 0,59 \mu\text{m}$$

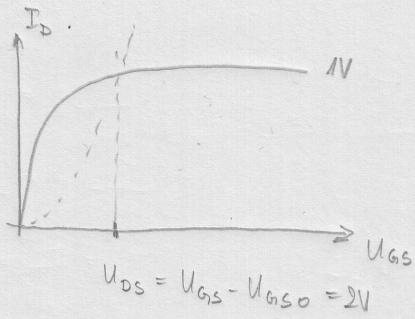


REVERZNO POL.

⑥



7)  $U_{DS} > 0 \Rightarrow NMOS$

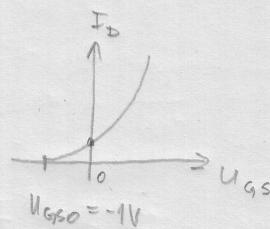


$$U_{GS} - U_{GSO} = 2V$$

$$U_{GSO} = U_{GS} - 2 = 1 - 2 = -1V$$

NMOS  
 $U_{GSO} < 0 \} OSIROMAŠENO$

$$U_2: U_{GSO} = 0 \Rightarrow |I_D| > 0 \quad OSIROMAŠENO$$



**PITANJA**

	<b>A</b>	<b>B</b>	<b>C</b>	<b>D</b>
<b>1</b>	D	B	E	C
<b>2</b>	A	D	B	E
<b>3</b>	B	E	C	A
<b>4</b>	A	D	B	E
<b>5</b>	A	D	B	E
<b>6</b>	C	D	B	B
<b>7</b>	C	A	D	B